

Synthesis of CH₃NH₃PbI₃:ZnS Microrods

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Abstract

In the field of optoelectronics, perovskite is a promising material (OE). This study demonstrates the synthesis of CH₃NH₃PbI₃ perovskite ZnS for OE applications. The inclusion of ZnS in the perovskite material caused the bandgap to widen. The structural properties were investigated using XRD. The ZnS showed a significant effect on the structure of perovskite. Though fine crystallinity was maintained, the addition of ZnS caused cell contraction hence decreased the volume.

Keywords: Perovskite, zinc sulfide, composite, thin-film, spin coating, micro rod.

1. Introduction

A material's optical and electrical characteristics are heavily influenced by its crystal structure and bandgap. A substance can produce a variety of crystal shapes depending on the crystal growth conditions (one, two, or three dimensional). The diameters determine the bandgap of micro/nanorod formations. As a result, changing the diameters may modify the bandgap, allowing them to be used in a variety of applications. Perovskite micro rods (MRs), nanorods (NRs), and nanowires (NWs) can increase performance in a wide range of OE applications because to their unique crystal structure and tunable bandgap. Due to improved solar performance and other OE applications, one-dimensional (1D) OMPs have become fairly common [1].

Scientists are also interested in composite perovskites research. To improve performance and stability, other materials called composites have been added to the pure perovskites structure. Perovskite composite with metal sulfide, for example, is a new research avenue for improving optical performance that began in 2017. Chen et al. presented a MAPI:CdS composite film for SCs that was made using the precursor blending approach and shown improved photovoltaic performance [2]. In the presence of CdS, the absorbance rose somewhat between 500nm and 750nm, indicating an increase in the absorption coefficient. They failed to show the shape of MAPI crystals, and Cd is a highly hazardous substance that should be avoided. Wang et al. created PbS quantum dots embedded

on MAPI NWs for photodetection purposes in 2019 [3]. Pure MAPI rods had lower absorbance across a wide range of the visible spectrum, whereas composite nano-rods had higher absorbance. These findings revealed that adding metal sulfide into OMPs can improve optical performance, paving a new path in perovskite research and motivating us to continue our work. The synthesis of MAPI MRs using ZnS composite is described here. With a high absorption coefficient, ZnS is potentially a promising material for OE applications [4,5]. s

2. Experimental Details

2.1. Materials

Methylamine (MA) solution 33wt%, hydroiodic acid (HI) 57%, PbI_2 (99%), diethyl ether, N, N-Dimethylformamide (DMF), Zinc chloride, and thiourea were used in this research process.

2.2. Preparation of MAPI and MAPI:ZnS composite

In an ice bath, MA and HI solutions in a (1:1) molar ratio were mixed and stirred for 1 hour (between 0 and 4 degrees Celsius). After stirring, the solution was kept in the ice bath for another 2 hours. The solution was dried at 60°C in an evaporating oven, giving an MAI crystal, which was then washed with diethyl ether multiple times to remove impurities, yielding white MAI crystals. PbI_2 and MAI were completely dissolved in DMF at an equimolar ratio and dried at 60°C to form MAPI crystals. The MAPI crystals that have been created are shown in Figure 1. The precursor blending solution technique was used to make MAPI: ZnS-based composite [2,6].

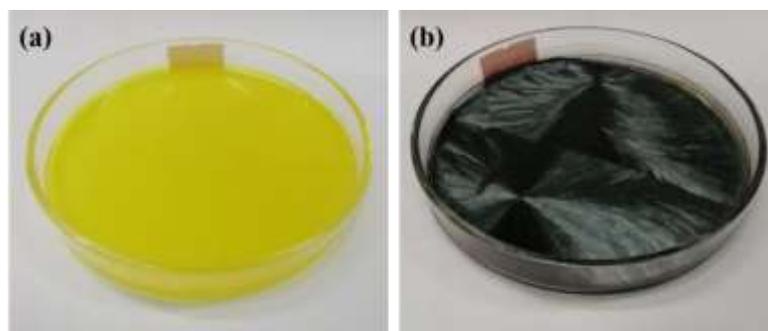


Figure-1: (a) MAPI solution in DMF, (b) MAPI dried crystals.

3. Result and Discussion

3.1. XRD Analysis

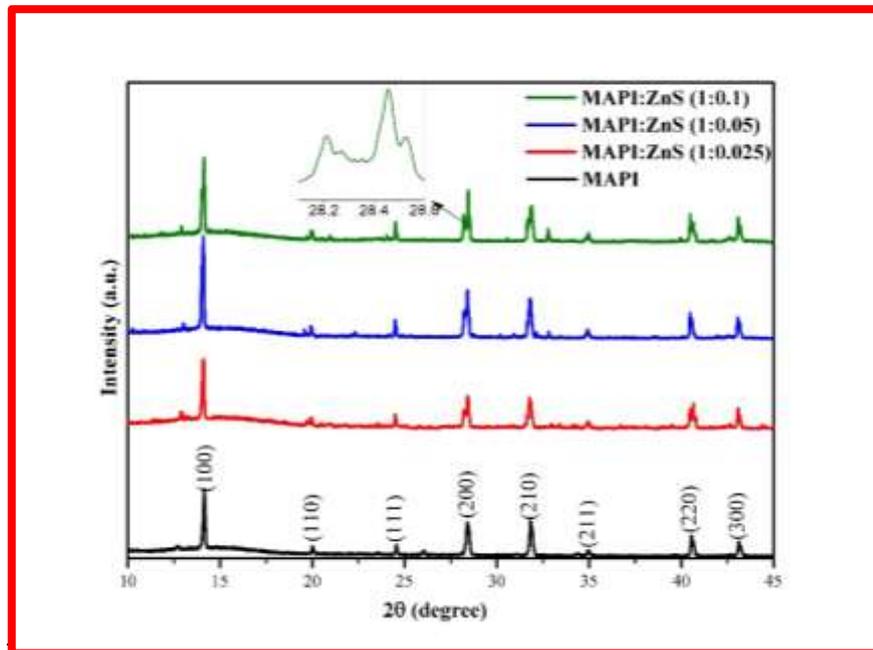


Figure-3: XRD spectra of MAPI and MAPI:ZnS composites

Figure 3 shows the XRD patterns for the samples MAPI and ZnS doped MAPI. The MAPI diffraction peaks were found at 14.08°, 19.95°, 24.49°, 28.34°, 31.75°, 34.85°, 40.46°, and 43.05°, which correspond to the (100), (101), (111), (200), (201), (211), (202), (300) planes [7,8].

The addition of ZnS induces structural deformation in MAPI crystals, as evidenced by a small shift in the diffraction peaks in the spectra. Because ZnS is produced via the chemical interaction of ZnCl₂ and Thiourea ($ZnCl_2 + CH_4N_2S = ZnS + CH_4N_2 + Cl_2$), the lack of ZnCl₂ peaks in the spectra confirms the production of ZnS in the perovskite sample.

Table-1: Lattice parameters of MAPI and MAPI:ZnS composite

Material	Lattice parameters (Å)			Phase ($\alpha = \beta = \gamma = 90^\circ$)	Cell volume (Å ³)
	a	b	c		
MAPI	6.3087	6.3087	6.3087	Cubic	250.15
MAPI: ZnS	6.2973	6.2973	6.2973	Cubic	249.72

(1:0.025)					
MAPI: ZnS (1:0.05)	6.2747	6.2747	4.4074	Tetragonal	173.53
MAPI: ZnS (1:0.1)	4.4486	4.4486	6.3038	Tetragonal	124.75

4. Conclusions

The spin coating technique was used to successfully synthesize MAPI and MAPI:ZnS composite MRs with various molar ratios in this study. MAPI's structural properties changed when the ZnS molar ratio changed. Fine crystallinity is seen in the XRD graphs and is present in the produced samples. Variable ZnS stoichiometry caused an alteration in the crystal structure with a phase transition. The lattice parameter as well the volume of the unit cell decreased with increasing ZnS.

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